

# S8081000G

- IR Laser Diode
- 808 nm, 1000 mW
- Multi mode
- TO9 with integrated photodiode





# Description

**S8081000G** is an IR laser diode, typically emitting at 808 nm, with a wide operating temperature range of up to 50°C, low operating current and low divergence angle. **S8081000G** comes in 9 mm TO-Can package with integrated monitor photodiode.

# Maximum Rating\* (TCASE = 25°C)

Parameter	Cumbal	Val	Unit		
rarameter	Symbol	Min.	Max.	Onit	
Optical Output Power*1	$P_{MAX}$		1100	mW	
Reverse Voltage	$V_{R}$		2	V	
Operating Temperature*1	$T_{OPR}$	- 10	+ 50	°C	
Storage Temperature	T <sub>STG</sub>	- 10	+ 85	°C	
Soldering Temperature (max. 3s)	$T_{SOL}$		+ 260	°C	

<sup>\*1</sup> operating at maximum ratings may influence the life time

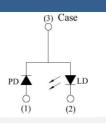
# Electro-Optical Characteristics (TCASE = 25°C)

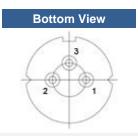
Parameter		Symbol	Values			l locit
			Min.	Тур.	Max.	Unit
Peak Wavelength		<b>λ</b> P	803	808	813	nm
Optical Output Power		<i>P</i> o		1000		mW
Operating Voltage		VF		2.0	2.2	V
Threshold Current		<i>I</i> th		220		mA
Operating Current		<i>I</i> F		1200	1500	mA
Monitor Current		<i>I</i> <sub>M</sub>		0.9		mA
Slope Efficiency		η	0.95	1.1		W/A
Beam Divergence (FWHM)	parallel	ΘII		8		deg.
	perpendicular	θΤ		28		deg.



# **Electrical Connection**

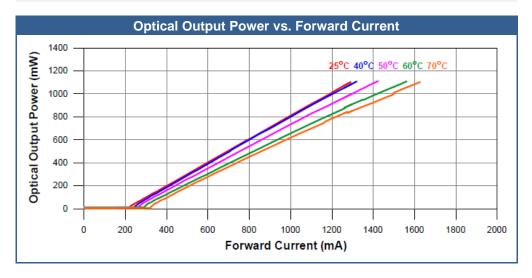
	Pin Configurati	(
Pin #	Function	
Pin 1	PD Anode	
Pin 2	LD Cathode	
Pin 3	LD Anode, PD Cathode	

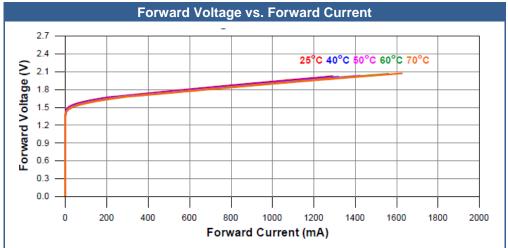


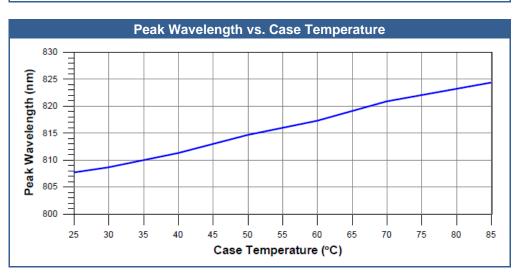




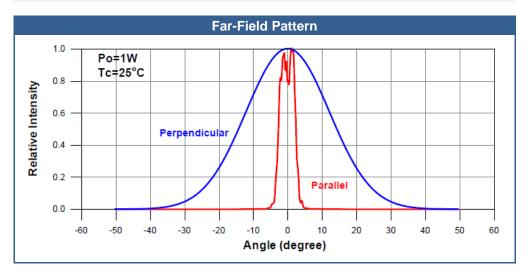
### **Performance Characteristics**

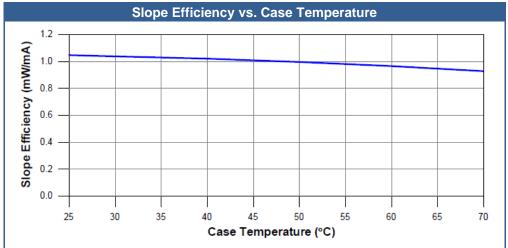


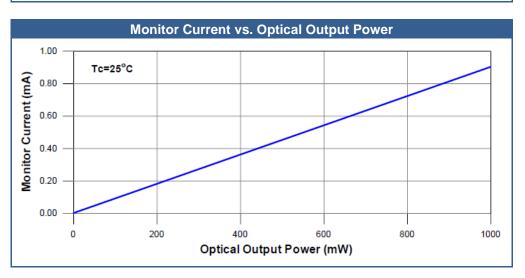




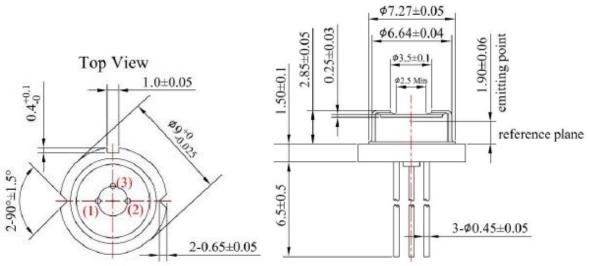
### **Performance Characteristics**







### **Outline Dimensions**



All dimensions in mm

#### **Precautions**

#### Safety

**Caution:** Laser light emitted from any laser diode may be **harmful to the human eye**. Avoid looking directly into the laser diode's aperture when the diode is in operation.

Note: The use of optical lenses with this laser diode will increase eye hazard

#### **ESD** caution

Always do handle laser diodes with extreme care to **prevent electrostatic discharge**, the primary cause of unexpected diode failure. To prevent ESD related failures, it is strongly advised to always **wearing wrist straps**, and **grounding all applicable work surfaces**, when handling laser diodes

#### **Operating Considerations**

It is strongly advised to only operate this laser diode with a current source. The current of a laser diode is an exponential function of the voltage across it. **Usage of current regulated drive circuits is mandatory.** Laser diodes may be damaged by excessive drive currents or switching transients

It is advised, to operate the laser diode at the lowest temperature possible, and to never exceed maximum specifications as outlined in the datasheet. Device degradation will accelerate with increased temperature. Proper heat sinking will greatly enhance stability and life time of the laser diode

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The above specifications are for reference purpose only and subjected to change without prior notice.